

## isc Silicon NPN Power Transistor

2SD1632

## DESCRIPTION

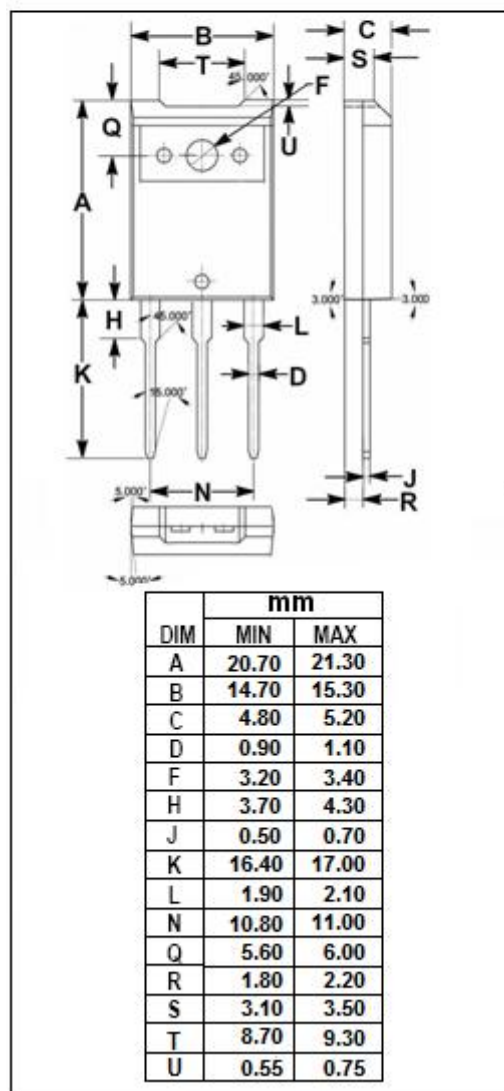
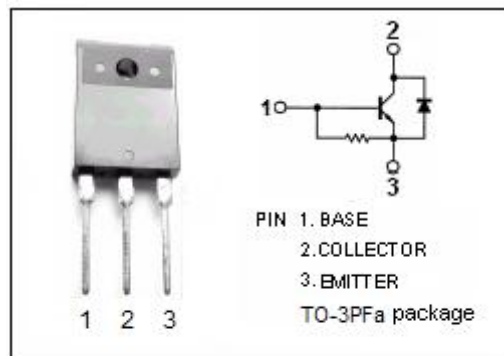
- Collector-Base Breakdown Voltage-  
:  $V_{CBO} = 1300V$  (Min.)
- High Switching Speed
- Built-in Damper Diode
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

## APPLICATIONS

- Designed for horizontal deflection output applications

ABSOLUTE MAXIMUM RATINGS( $T_a = 25^\circ C$ )

SYMBOL	PARAMETER	VALUE	UNIT
$V_{CBO}$	Collector- Base Voltage	1300	V
$V_{CES}$	Collector-Emitter Voltage	1300	V
$V_{EBO}$	Emitter-Base Voltage	5	V
$I_C$	Collector Current-Continuous	4	A
$I_{CM}$	Collector Current-Peak	15	A
$I_{BM}$	Base Current-Peak	3.5	A
$P_C$	Collector Power Dissipation @ $T_c = 25^\circ C$	70	W
$T_J$	Junction Temperature	130	$^\circ C$
$T_{stg}$	Storage Temperature Range	-55~130	$^\circ C$



**isc Silicon NPN Power Transistor****2SD1632****ELECTRICAL CHARACTERISTICS****T<sub>c</sub>=25°C unless otherwise specified**

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> = 200mA; I <sub>C</sub> = 0	5			V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 3A; I <sub>B</sub> = 1A			1.0	V
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	I <sub>C</sub> = 3A; I <sub>B</sub> = 1A			1.5	V
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = 750V; I <sub>E</sub> = 0 V <sub>CB</sub> = 1300V; I <sub>E</sub> = 0			50 1.0	μ A mA
h <sub>FE</sub>	DC Current Gain	I <sub>C</sub> = 3A; V <sub>CE</sub> = 10V	5		15	
V <sub>ECF</sub>	C-E Diode Forward Voltage	I <sub>F</sub> = 4A			2.2	V

**Switching times**

t <sub>stg</sub>	Storage Time	I <sub>C</sub> = 3A; I <sub>B(end)</sub> = 1A; L <sub>leak</sub> = 5 μ H			9.0	μ s
t <sub>f</sub>	Fall Time				0.8	μ s

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